

### Features

- Step-down Converter with very high Efficiency (> 91%)
- Input Voltage Range +8 VDC to +27 VDC
- 1.2 VDC to 5.1 VDC Output, up to 3 A
- Fast Transient Response
- Remote ON/OFF
- Overload Protection
- Low Output Noise
- Standby Current only 100  $\mu$ A
- Small SIL- or DIP-Package
- 2 Years Product Warranty



This new generation of step-down converters provides designers with a cost-effective solution for converting 8 VDC to 27 VDC voltage down to 1.25 VDC to 5 VDC. To achieve highest efficiency, these dc/dc converters are using advanced circuit techniques, as amorphous ferrite, solid aluminum capacitors and a synchronous commutation IC.

The TSI-24 series needs no further external components to operate within its specifications. A very high efficiency allows operation without additional heatsink. This product finds many applications in distributed powersystems where voltage conversion at the point of load is required.

### Models

Ordercode	Input voltage range	Output voltage	Output current max.	Efficiency typ.	Package
TSI-24-5.0S3ROP TSI-24-5.0S3ROF	8 – 27 VDC	* + 3.3 VDC	3000 mA	91.0 %	SIP DIP

\* Output adjustable 1.2 to 5.1 VDC

### Input Specifications

Input current (no load)	1 mA max.
Input current (at full load)	1350 mA max. (12 Vin)
Stand-by current	100 µA typ

### Output Specifications

Output voltage tolerance	± 3.0 %	
Output voltage adjustment	+1.2 VDC to +5.1 VDC	
Output voltage selection	+1.2 Vout +3.3 Vout +5.0 Vout	V.ADJ (pin 14) link wire to +Vout (pin 17,18) V.ADJ (pin 14) = open VADJ (pin 14) connected via 20 kOhm resistor to +Vout (pin 17,18)
Regulation	- Input variation - Load variation 0 – 100 %	± 0.3 % < 3.0 %
Ripple and noise (20 MHz Bandwidth)	35 mVpk-pk typ.	
Transient response time (with 220 µF output cap.)	50 % Load change: Vout over-/undershoot:	80 µsec typ. 70 mV typ.
Temperature coefficient	± 0.01 % / °C	
Short circuit protection	>105% constant current	
Capacitive load	20'000 µF	
Remote ON/OFF control	ON = Pin 5 (ON/OFF Pin) to pin 4 (GND) open OFF = Pin 5 (ON/OFF Pin) to pin 4 (GND) short	

### General Specifications

Temperature ranges	- Operating - Storage Derating above 50 °C	- 10 °C ... +71 °C - 25 °C ... +85 °C 3 % / °C
Humidity (non condensing)	30 – 95 % rel H	
Reliability, calculated MTBF (MIL-HDBK-217 F)	> 350'000 h at 40 °C	
Isolation Input/Output	none	
Switching frequency	150 kHz typ. (PWM modulation)	

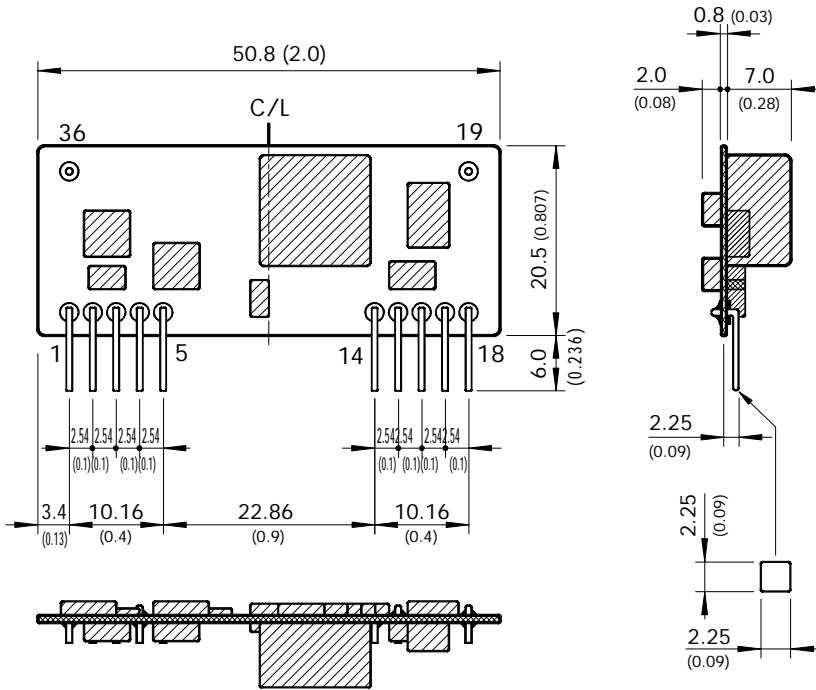
### Physical Specifications

Vibration	5 to 10 Hz amplitude 10 mm pk-pk 10 to 55 Hz acceleration 2 G
Shock	acceleration 20 G max. time 11 ms
Package weight	13 g (0.46 oz)
Soldering temperature	max. 260°C max. / 10 sec.

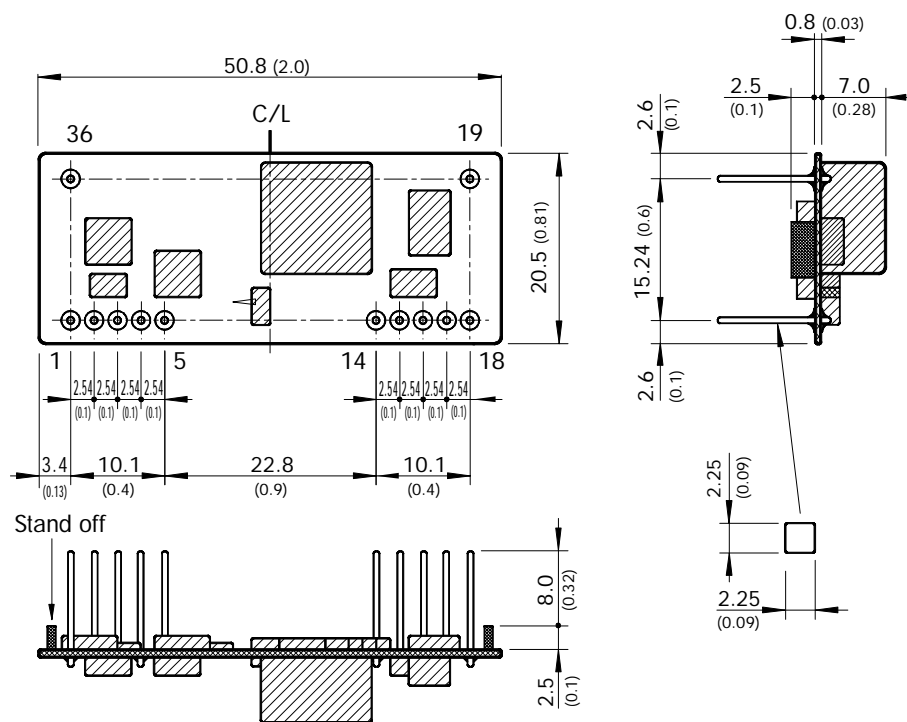
All specifications valid at nominal input voltage, full load and +25°C after warm-up time unless otherwise stated.

**Outline Dimensions mm (inches)**

**SIP package**



**DIP package**



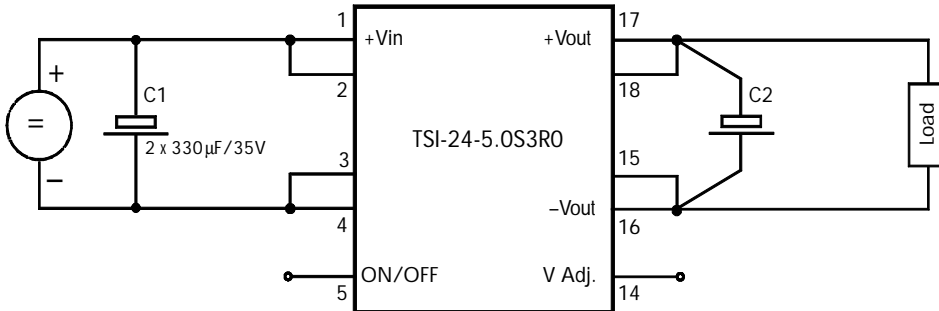
**Pin-Out**

Pin	DIP	SIP
1	+V Input (Vcc)	+V Input (Vcc)
2	+V Input (Vcc)	+V Input (Vcc)
3	-V Input (GND)	-V Input (GND)
4	-V Input (GND)	-V Input (GND)
5	Remote on/off	Remote on/off
14	V Output adj	V Output adj
15	-V Output	-V Output
16	-V Output	-V Output
17	+V Output	+V Output
18	+V Output	+V Output
19	No function	No pin
36	No function	No pin

Specifications can be changed without notice

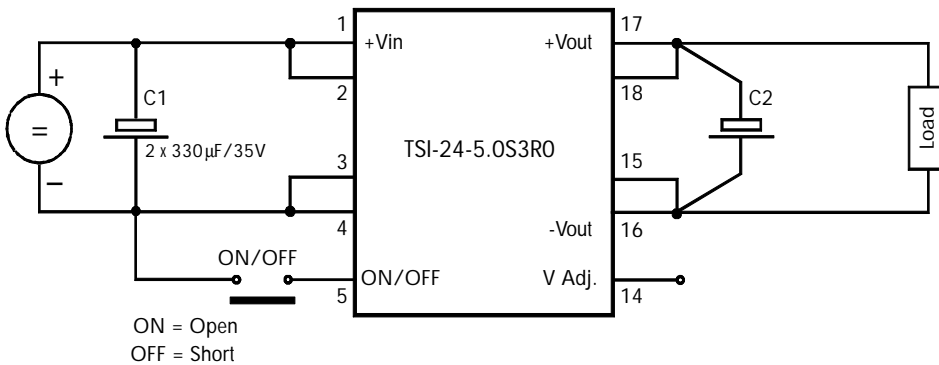
**Connections**

Normal Connection (Standard)



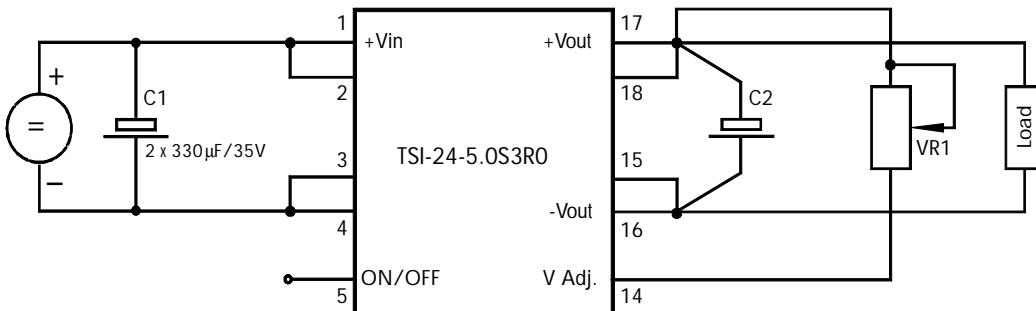
Value of C2:  
 Vout: 1.2 V...2.1V 2 x 330 µF /35V  
 Vout: 2.1 V...3.1V 2 x 220 µF /35V  
 Vout: 3.1V...5.1V 2 x 150 µF /35V

Remote ON/OFF Connection



Value of C2:  
 Vout: 1.2 V...2.1V 2 x 330 µF /35V  
 Vout: 2.1 V...3.1V 2 x 220 µF /35V  
 Vout: 3.1V...5.1V 2 x 150 µF /35V

Output Voltage Adjustment Connection



Value of C2:  
 Vout: 1.2 V...2.1V 2 x 330 µF /35V  
 Vout: 2.1 V...3.1V 2 x 220 µF /35V  
 Vout: 3.1V...5.1V 2 x 150 µF /35V

Capacitors:  
 C1 ==> SXE series Mfg. Nippon Chemi-Con  
 C2 ==> SH series Mfg. Sanyo OS-CON  
 C2 ==> FH series Mfg. Nippon Chemi-Con

$$VR1 = 5.1 \cdot (V_{out} - 1.0) - 1.2$$

VR1 = kOhm

Vout = VDC

Specifications can be changed without notice